

Bipolar Transistor

50 V, 5 A, Low $V_{CE(sat)}$, NPN TO-220-3L

2SD1060

Features

- Low Collector-to-Emitter Saturation Voltage : $V_{CE(sat)} = 0.3 \text{ V max}$ /
 $I_C = 3 \text{ A}$, $I_B = 0.3 \text{ A}$

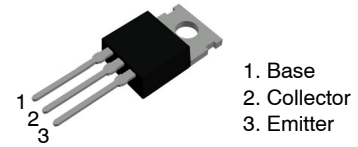
Applications

- Suitable for Relay Drivers, High-Speed Inverters, Converters, and Other General Large-Current Switching

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

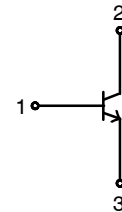
Symbol	Parameter	Conditions	Ratings	Unit
V_{CBO}	Collector-to-Base Voltage	–	60	V
V_{CEO}	Collector-to-Emitter Voltage	–	50	V
V_{EBO}	Emitter-to-Base Voltage	–	6	V
I_C	Collector Current	–	5	A
I_{CP}	Collector Current (Pulse)	–	9	A
P_C	Collector Dissipation	–	1.75	W
		$T_C = 25^\circ\text{C}$	30	W
T_J	Junction Temperature	–	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	–	–55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

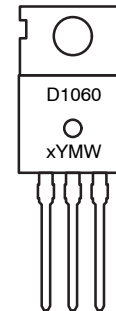


TO-220, 3L
CASE 221AU

ELECTRICAL CONNECTION



MARKING DIAGRAM



D1060x = Specific Device Code
 x = S/R
 Y = Year of Production
 M = Assembly Operation Month
 W = Work Week Number

ORDERING INFORMATION

Device	Package	Shipping
2SD1060R-1E	TO-220-3L (Pb-Free)	50 Units / Tube
2SD1060S-1E	TO-220-3L (Pb-Free)	50 Units / Tube

2SD1060

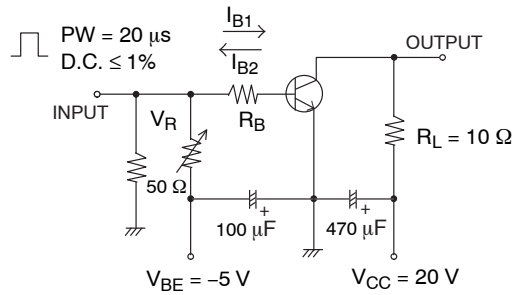
ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Symbol	Parameter	Conditions	Ratings			Unit
			Min	Typ	Max	
I _{CBO}	Collector Cutoff Current	V _{CB} = 40 V, I _E = 0 A	–	–	0.1	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4 V, I _C = 0 A	–	–	0.1	mA
h _{FE1}	DC Current Gain	V _{CE} = 2 V, I _C = 1 A	100*	–	280*	
h _{FE2}		V _{CE} = 2 V, I _C = 2 A	80	–	–	
f _T	Gain-Bandwidth Product	V _{CE} = 5 V, I _C = 1 A	–	30	–	MHz
C _{ob}	Output Capacitance	V _{CB} = 10 V, f = 1 MHz	–	100	–	pF
V _{CE(sat)}	Collector-to-Emitter Saturation Voltage	I _C = 3 A, I _B = 0.3 A	–	–	0.3	V
V _{(BR)CBO}	Collector-to-Base Breakdown Voltage	I _C = 1 mA, I _E = 0 A	60	–	–	V
V _{(BR)CEO}	Collector-to-Emitter Breakdown Voltage	I _C = 1 mA, R _{BE} = ∞	50	–	–	V
V _{(BR)EBO}	Emitter-to-Base Breakdown Voltage	I _E = 1 mA, I _C = 0 A	6	–	–	V
t _{on}	Turn-ON Time	See specified Test Circuit	–	0.1	–	μs
t _{stg}	Storage Time		–	1.4	–	μs
t _f	Fall Time		–	0.2	–	μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

* The 2SD1060 is classified by 1 A h_{FE} as follows:

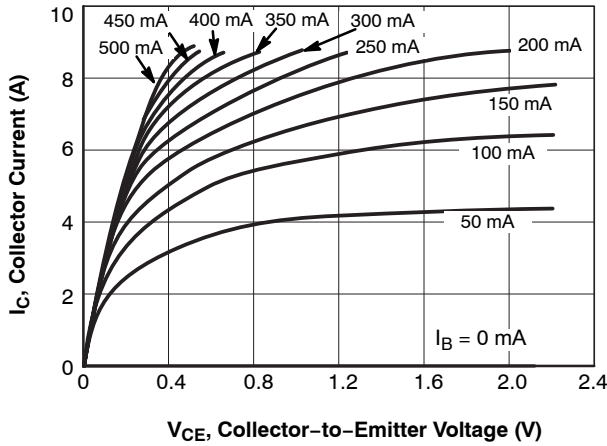
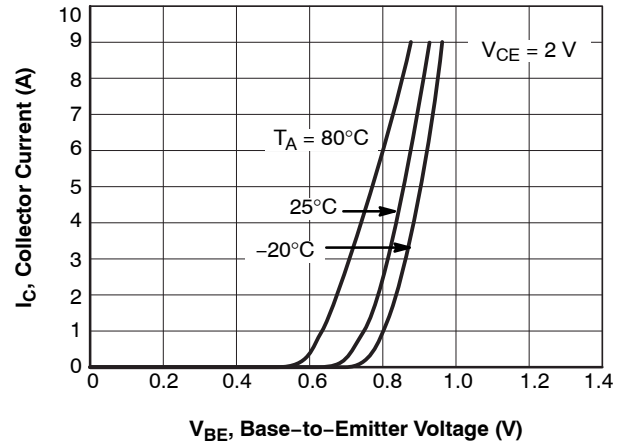
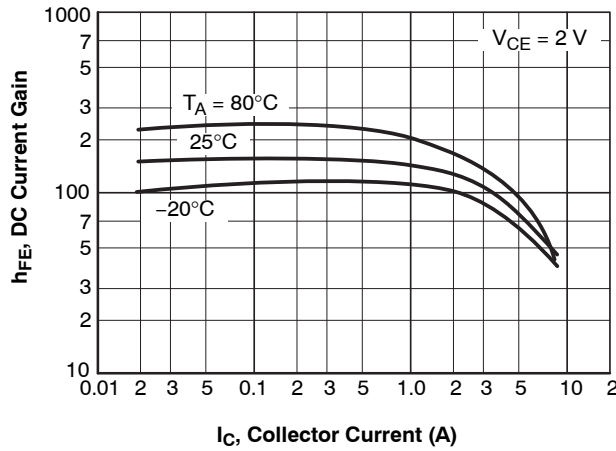
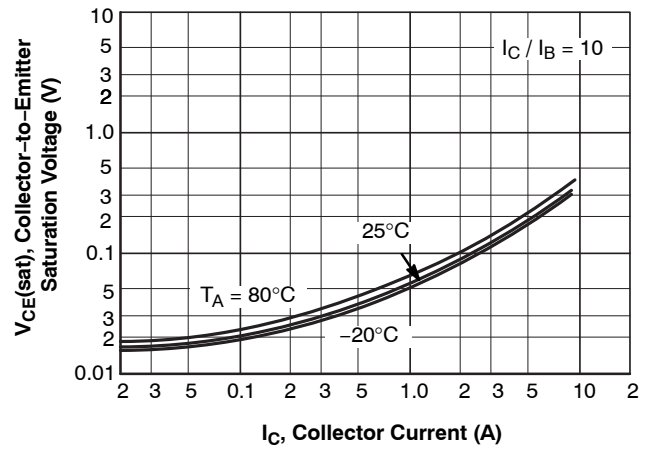
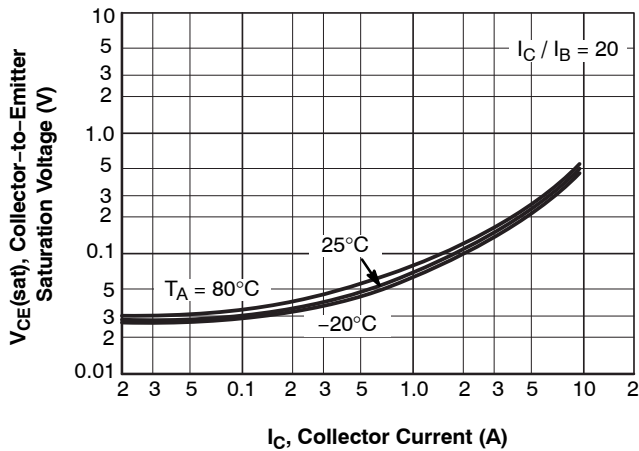
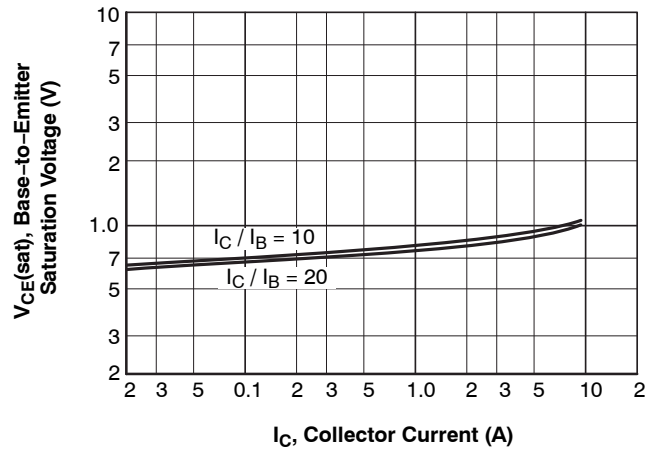
Rank	R	S
h _{FE}	100 to 200	140 to 280



$$I_C = 10I_{B1} = -10I_{B2} = 2 \text{ A}$$

Figure 1. Switching Time Test Circuit

TYPICAL CHARACTERISTICS

Figure 2. $I_C - V_{CE}$ Figure 3. $I_C - V_{BE}$ Figure 4. $h_{FE} - I_C$ Figure 5. $V_{CE(sat)} - I_C$ Figure 6. $V_{CE(sat)} - I_C$ Figure 7. $V_{BE(sat)} - I_C$

TYPICAL CHARACTERISTICS (continued)

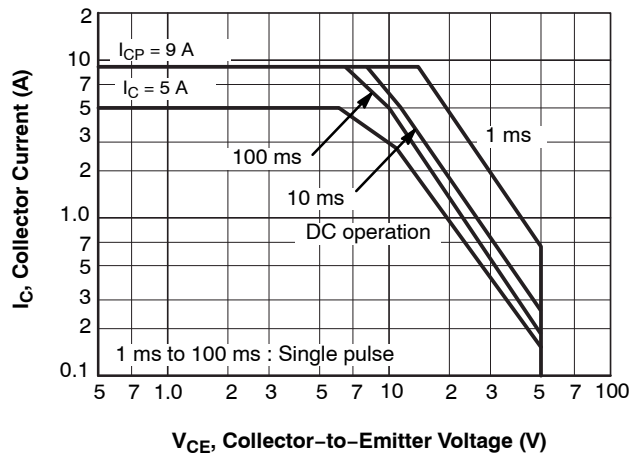


Figure 8. ASO

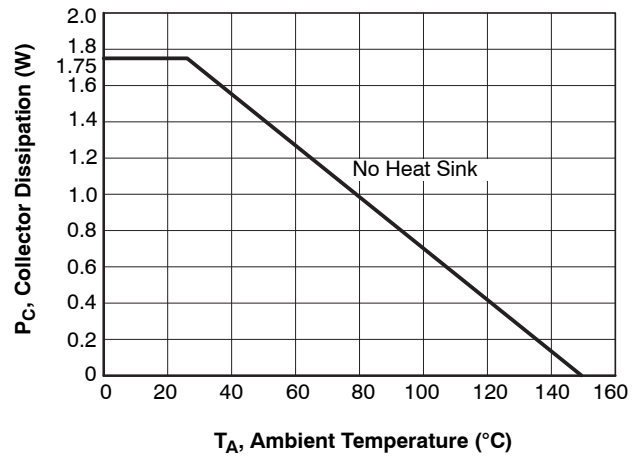


Figure 9. $P_C - T_A$

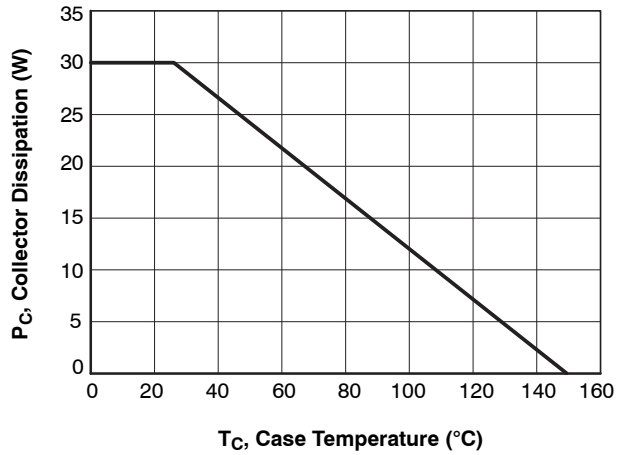
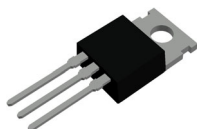
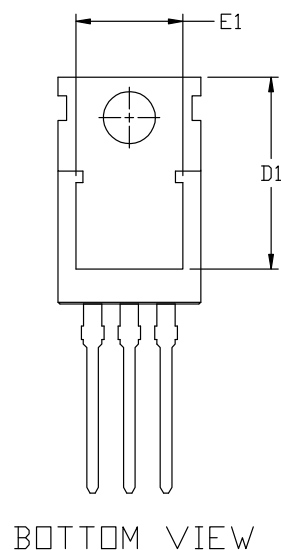
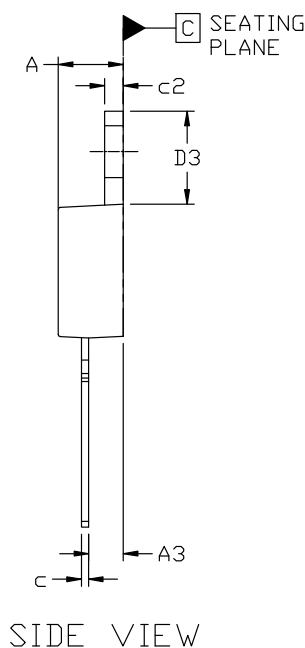
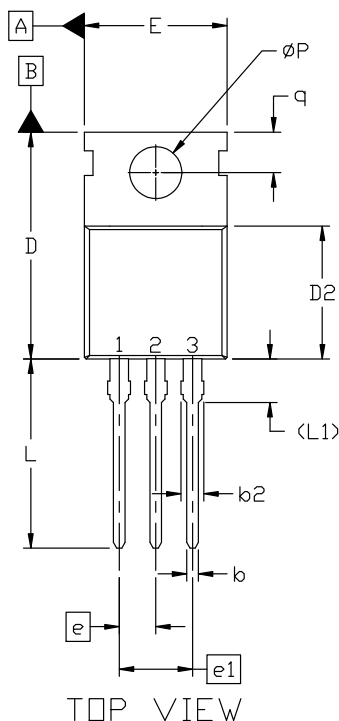


Figure 10. $P_C - T_C$



TO-220, 3L, 10.00x9.20x4.50, 2.45P
CASE 221AU
ISSUE B

DATE 18 JAN 2024



DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	4.30	4.50	4.70
A3	2.20	2.40	2.60
b	0.70	0.80	0.90
b2	1.17	1.27	1.37
c	0.45	0.50	0.60
c2	1.20	1.30	1.40
D	15.50	15.70	15.90
D1	13.10	13.30	13.50
D2	9.00	9.20	9.40
D3	6.30	6.50	6.70
E	9.80	10.00	10.20
E1	---	---	8.90
e	2.54 BSC		
e1	5.08 BSC		
L	12.88	13.08	13.28
L1	2.80	3.00	3.20
ϕP	3.40	3.60	3.80
q	2.70	2.80	2.90

NOTES:

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
2. ALL DIMENSIONS ARE IN MILLIMETERS.
3. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
4. MAXIMUM WIDTH FOR F102 DEVICES = 1.37MM.
5. DIMENSION "A3" TO BE MEASURED IN THE REGION DEFINED BY L1.

DOCUMENT NUMBER:	98AON78949E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	TO-220, 3L, 10.00x9.20x4.50, 2.45P	PAGE 1 OF 1

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at
www.onsemi.com/support/sales